

Features

Input voltage:2.5V~6.5V

 Output range:1.0V~3.3V (customized by every 0.1V step)

Output current: 300mA

PSRR: 75dB @1KHz

Dropout voltage:220mV @ IOUT=200mA

Quiescent current: 35µA Typ.

• Shut-down current: <1μA

Recommend capacitor:1µF

Ultra Low Output Noise:20µVRMS

Applications

- MP3/MP4 Players
- Cellphones, radiophone, digital cameras
- Bluetooth, wireless handsets
- Others portable electronics device

General Description

The TX6213 is a high accuracy, low noise, high speed, low dropout CMOS Linear regulator with high ripple rejection and fast discharge function. The devices offer a new level of cost effective performance in cellular phones, laptop and notebook computers, and other portable devices.

TX6213 can provide product selections of output value in the range of 1.0V~3.3V by every

0.1V step.

The current limiter's fold-back circuit also operates as a short circuit protection and an output current limiter at the output pin.

The TX6213 regulators are available in standard SOT23-5L and DFN1 \times 1-4 packages. Standard products are Pb-free and Halogen-free.

Selection Table

Part No.	Package	Temperature	Tape & Reel
TX6213-XXM5R	SOT23-5L	-40 ~ +85°C	3000/REEL
TX6213-XXFCR	DFN1×1—4	-40 ~ +85°C	10000/REEL

Note: XX indicates 1.0V~3.3V by 0.1V step. For example, 28 means product outputs 2.8V

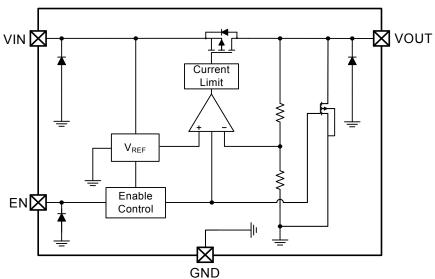
Order Information

TX6213-112

Designator	Description
	Voltage version:
	XX: 1.0V~3.3V by 0.1V step
	Example:
	28: 2.8V
	Package:
2	M5R: SOT23-5L
	FCR:DFN1×1—4

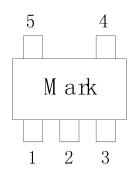


Block Diagram



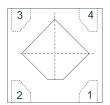
Pin Assignment

SOT23-5 (Top View)



PIN NO	SYMBOL	I/O	DESCRIPTTION
SOT23-5L	STWIBOL	"0	DESCRIPTION
1	VIN	Power	Input
2	GND	Ground	Ground
3	EN	I	Enable(Active high, not floating)
4	NC	/	Not connected
5	VOUT	0	Output

DFN1x1-4L (Top View)



PIN NO	SYMBOL	I/O	DESCRIPTTION
DFN1×1—4	STWIDOL	1/0	DESCRIPTION
1	VOUT	0	Output
2	GND	Ground	Ground
3	CE	I	Enable(Active high, not floating)
4	VIN	Power	Input



Absolute Maximum Ratings

Input Voltage0.3V to	8V Storage Temperature55°C to 150°C
Output Current450mA	Package Lead Soldering Temperature260 $^{\circ}\mathrm{C}$
Operating Temperature40°C to 8	5 ℃ Junction Temperature40 ℃ to 125 ℃
Ambient Temperature -40°C to 8	S°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Thermal Information

Symbol	Parameter	Package	Max.	Unit
θ _{JA}	Thermal Resistance (Junction to Ambient) (Assume no ambient	SOT23-5	500	°C/W
JA	airflow, no heat sink)	DFN1×1—4	300	C/VV
P _D	Power Dissipation	SOT23-5	0.30	W
L LD	Fower Dissipation	DFN1×1—4	0.25	VV

Note: P_D is measured at Ta= $25\,^{\circ}\!\mathrm{C}$

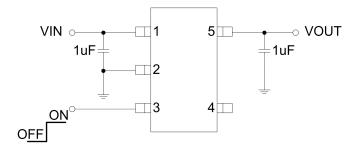
Electrical Characteristics

The following specifications apply for $V_{\text{OUT}}\text{=}2.8\text{V}, T_{\text{A}}\text{=}25\,^{\circ}\text{C}$, unless specified otherwise.

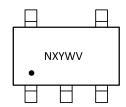
SYMBOL	ITEMS	CONDITIONS	MIN	TYP	МАХ	UNIT
V_{IN}	Input Voltage				6.5	V
.,		V _{OUT} <2V V _{IN} =2.7V, I _{OUT} =1mA	-3	V _{OUT}	3	
V _{OUT}	Output Range	V _{ouт} ≥2V, I _{ouт} =1mA	-2	V _{out}	2	%
ΙQ	Quiescent Current	V _{OUT} =2.8V, I _{OUT} =0		35		μΑ
I _{LIMIT}	Current Limit	V _{IN} =V _{EN} =4.5V		450		mA
		V _{OUT} =2.8V, I _{OUT} =200mA		220	250	
V_{DROP}	Dropout Voltage	V _{OUT} =2.8V, I _{OUT} =300mA		320	350	mV
ΔV _{LINE}	Line Regulation	V _{IN} =2.7~5.5V,I _{OUT} =1mA		0.01	0.15	%/V
ΔV_{LOAD}	Load Regulation	V _{OUT} =2.8V, I _{OUT} =1~300mA		80	100	mV
I _{SHORT}	Short Current	V_{EN} = V_{IN} , V_{OUT} Short to GND with 1Ω		60		mA
DCDD	Power Supply Rejection	$V_{IN}=5V_{DC}+0.5V_{P-P}$, $F=1KHz$, $I_{OUT}=10mA$		75		-ID
PSRR	Rate	V _{IN} =5V _{DC} +0.5V _{P-P} ,F=1MHz, I _{OUT} =10mA		55		dB
V_{ENH}	EN logic high voltage	V _{IN} =5.5V, I _{OUT} =1mA	1.2		V _{IN}	V
V_{ENL}	EN logic low voltage	V _{IN} =5.5V, V _{OUT} =0V			0.4	V
I _{EN}	EN Input Current	V _{EN} = 0 to 5.5V			1.0	μΑ
e _{NO}	Output Noise Voltage	10Hz to 100KHz, C _{OUT} =1μF		20		μV _{RMS}



Application Circuits



Marking Description



"N": Product code, here use "L" stands for "TX6213"

"X": Package factory

"Y":Wafer foundry vendor.

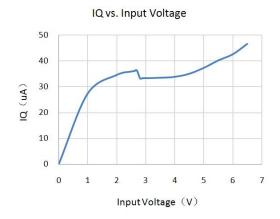
"W": The week of manufacturing. "A" stands for week1, "Z" stands for week 26, "a" stands for week 27, "z" stands for week 52.

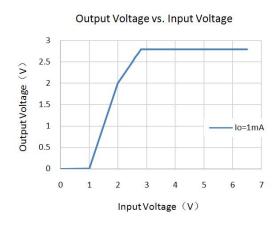
"V": Output voltage code.

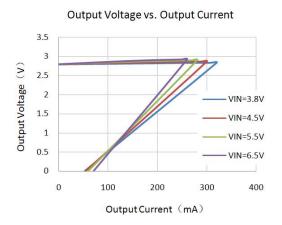


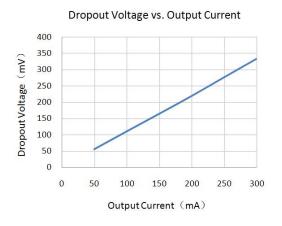
Typical Performance Characteristics

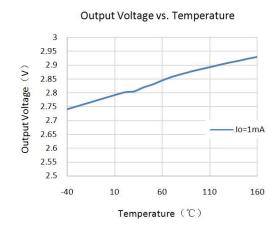
 C_{IN} =1uF, C_{OUT} =1uF, V_{IN} =4.5V, V_{OUT} =2.8VT_A=25°C, unless specified otherwise.

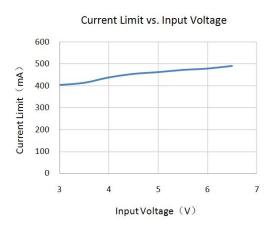




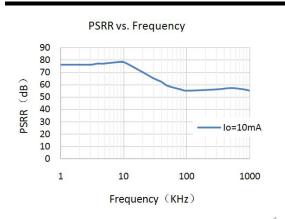




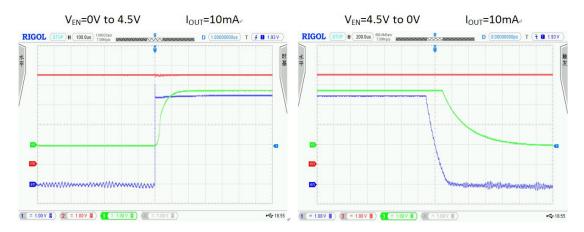




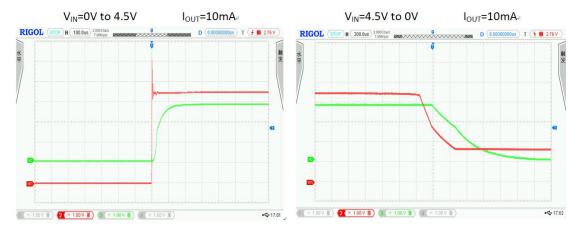




EN ON / OFF

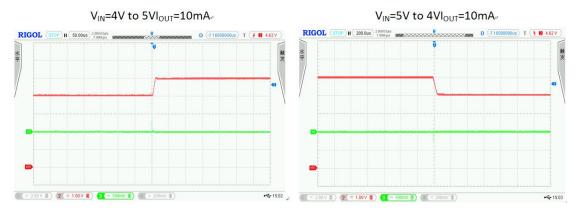


Power ON / OFF

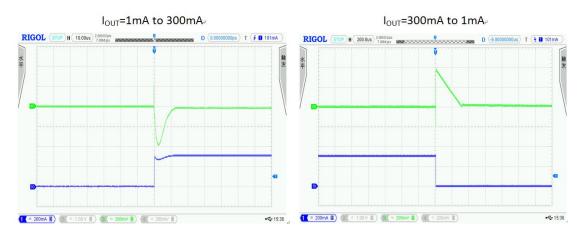




Line Transient



Load Transient





Application Information INPUT CAPACITOR

An input capacitor of ≥ 1.0µF is required between the VIN and GND pin. This capacitor must be located within 1cm distance from VIN pin and connected to a clear ground. A ceramic capacitor is recommended although a good quality tantalum or film may be used at the input. However, a tantalum capacitor can suffer catastrophic failures due to surge current when connected to a low impedance power supply (such as a battery or a very large capacitor).

There is no requirement for the ESR on the input capacitor, but the tolerance and temperature coefficient must be considered in order to ensure the capacitor work within the operation range over the full range of temperature and operating conditions.

OUTPUT CAPACITOR

In applications, it is important to select the output capacitor to keep in stable operation. The output capacitor must meet all the specified requirements in the following recommended capacitor table conditions in applications. The minimum capacitance for stability and correct operation is 0.6µF. The capacitance tolerance should be ±30% or better over the operation temperature range. The recommended capacitor type is X7R to meet the full device temperature specification.

The capacitor application conditions also include DC-bias, frequency and temperature. Unstable operation will result if the capacitance

drops below minimum specified value (see the next section Capacitor Characteristics).

The TX6213 is designed to work with very small ceramic output capacitors. A 1.0µF capacitor (X7R type) with ESR type between 0 and 400m Ω is suitable in the applications. X5R capacitors may be used but have a narrow temperature range. With these and other capacitor types (Y5V, Z6U) that may be used, selection relies on the range of operating conditions and temperature range for a specified application. It may also be possible to use tantalum or film capacitors at the output, but these are not as good for reasons of size and cost. It is also recommended that the output capacitor be located within 1cm from the output pin and return to a clean ground wire.

NO-LOAD STABILITY

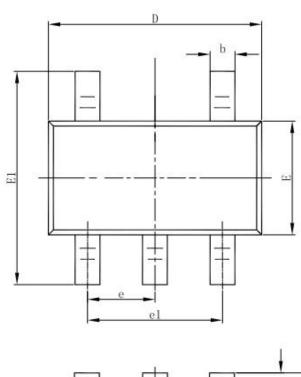
The TX6213 will remain stable and in regulation with no external load. This is especially important in CMOSRAM keep-alive applications.

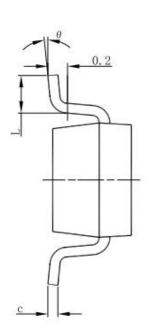
ON/OFF INPUT OPERATION

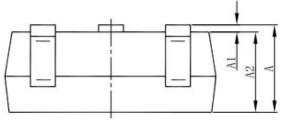
The TX6213 is turned off by pulling the EN pin low, and turned on by pulling it high. If this function is not used, the VEN pin should be tied to VIN to keep the regulator output on at all time. To assure proper operation, the signal source used to drive the VEN input must be able to swing above and below the specified turn-on/off voltage thresholds listed in the Electrical Characteristics section under VIL and VIH.



Package Information SOT23-5 Outline Dimensions



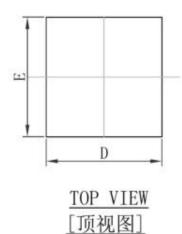


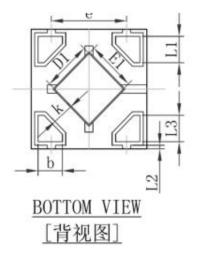


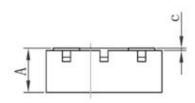
Comb a I	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
Е	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(BSC)		0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



DFN1×1-4 Outline Dimensions







Cumbal	Dimensions In Millimeters Min. Max.		Dimensions In Inches	
Symbol			Min.	Max.
Α	0.335	0.405	0.013	0.016
D	0.950	1.050	0.037	0.041
E	0.950	1.050	0.037	0.041
D1	0.370	0.470	0.015	0.019
E1	0.370	0.470	0.015	0.019
k	0.17	MIN.	0.007MIN.	
b	0.160	0.260	0.006	0.010
С	0.010	0.090	0.000	0.004
е	0.600	0.700	0.024	0.028
L1	0.185	0.255	0.007	0.010
L2	0.030 REF.		0.001	REF.
L3	0.185	0.255	0.007	0.010